

PS2381-1

4-PIN LSOP PHOTOCOUPLER OPERATING AMBIENT TEMPERATURE 115 °C

DESCRIPTION

The PS2381-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor.

This package is mounted in a plastic 4-pin LSOP (Long Mini-Flat Small Outline Package) for high density applications.

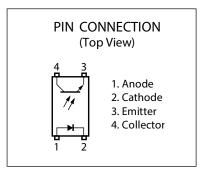
The package has shield effect to cut off ambient light.

FEATURES

- Operating ambient temperature: 115 °C
- Isolation distance (0.4 mm MIN.)
- High isolation voltage (BV = 5 000 Vr.m.s.)
- 4-pin LSOP (Long Mini-Flat Small Outline Package) type
- High-speed switching (tr = 4 μ s TYP., tf = 5 μ s TYP.)
- Embossed tape product: PS2381-1-F3: 3 000 pcs/reel
- Pb-Free product
- Safety standards
 - UL approved: UL 1577, Double protection
 - CSA approved: CAN/CSA-C22.2 No. 62368-1, Reinforced insulation
 - SEMKO approved: EN 62368-1, IEC 62368-1, Reinforced insulation
 - CQC approved: GB8898, GB4943.1, Reinforced insulation
 - VDE approved: DIN EN 60747-5-5 (Option)

APPLICATIONS

- Power supply
- FA/OA equipment

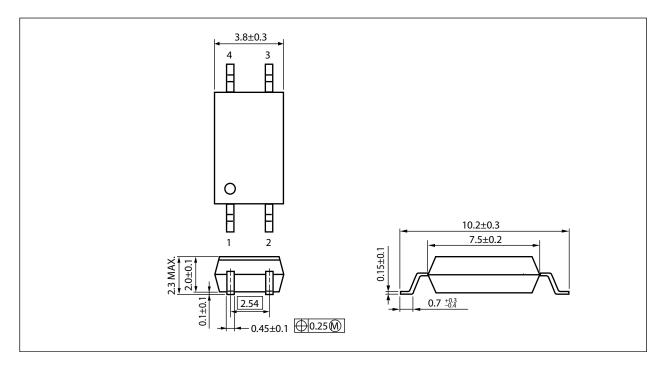


Start of mass production Jan.2010



R08DS0134EJ0201 Rev.2.01 Dec 25, 2020

PACKAGE DIMENSIONS (Unit: mm)

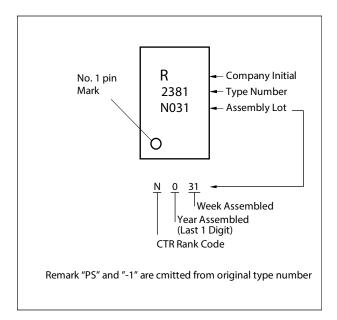


Weight (4-pin DIP) : 0.11 g (typ.)

PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	8 mm
Creepage Distance	8 mm
Isolation Distance	0.4 mm

MARKING EXAMPLE





ORDERING INFORMATION

Part Number	Order Number *1	Solder Plating Specification etc.	Packing Style	Safety Standard Approval	Application Part Number *2
PS2381-1	PS2381-1Y-AX	Pb-Free and	20 pcs (Tape 20 pcs cut)	Standard products	PS2381-1
PS2381-1-F3	PS2381-1Y-F3-AX	Halogen Free	Embossed Tape 3 000 pcs/reel	(UL, CSA, SEMKO, CQC approved)	
PS2381-1-V	PS2381-1Y-V-AX		20 pcs (Tape 20 pcs cut)	UL, CSA, SEMKO,	
PS2381-1-V-F3	PS2381-1Y-V-F3-AX		Embossed Tape 3 000 pcs/reel	CQC, DIN EN 60747-5-5 approved	

Notes: *1. When specifying CTR rank, please add "/CTR rank" after Order Number.

ex. L rank : PS2381-1Y-AX/L

*2. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	60	mA
	Reverse Voltage	VR	6	V
	Power Dissipation Derating*1	⊿P₀/°C	1.0	mW/°C
	Power Dissipation	P₀	100	mW
	Peak Forward Current*2	IFP	1.5	А
Transistor	Collector to Emitter Voltage	Vceo	80	V
	Emitter to Collector Voltage	VECO	7	V
	Collector Current	lc	50	mA
	Power Dissipation Derating*1	⊿Pc/°C	1.5	mW/°C
	Power Dissipation	Pc	150	mW
Isolation Vo	bltage ^{*3}	BV	5 000	Vr.m.s.
Total Power Dissipation		Ρτ	250	mW
Operating A	Ambient Temperature	TA	–40 to +115	°C
Storage Te	mperature	Tstg	–40 to +125	°C

Notes: *1. Derating from $T_A = 25 \ ^{\circ}C$.

*2. PW = 100 μ s, Duty Cycle = 1 %

*3. AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output. Pins 1-2 shorted together, 3-4 shorted together.



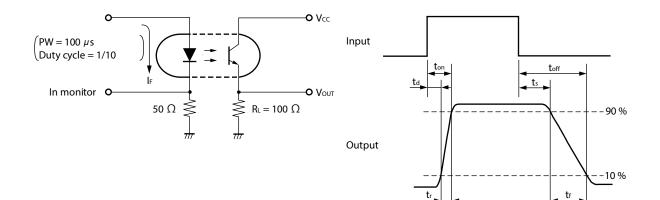
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	l⊧ = 5 mA		1.1	1.4	V
	Reverse Current	IR	V _R = 5 V			5	μA
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz		15		pF
Transistor	Collector to Emitter Dark Current	ICEO	IF = 0 mA, VCE = 24 V			100	nA
Coupled	Current Transfer Ratio	CTR	I⊧ = 5 mA, Vc⊧ = 5 V	50	100	400	%
	(Ic/IF)*1		I⊧ = 1 mA, Vcε = 5 V	10	50		
	Collector Saturation Voltage	VCE (sat)	I⊧ = 10 mA, Ic = 2 mA			0.3	V
	Isolation Resistance	RI-0	VI-0 = 1 kVDC	10 ¹¹			Ω
	Isolation Capacitance	CI-O	V = 0 V, f = 1 MHz		0.4		pF
	Rise Time ^{*2}	tr	Vcc = 5 V, Ic = 2 mA,		4		μs
	Fall Time ^{*2}	tr	R∟ = 100 Ω		5		

Notes: *1. CTR rank

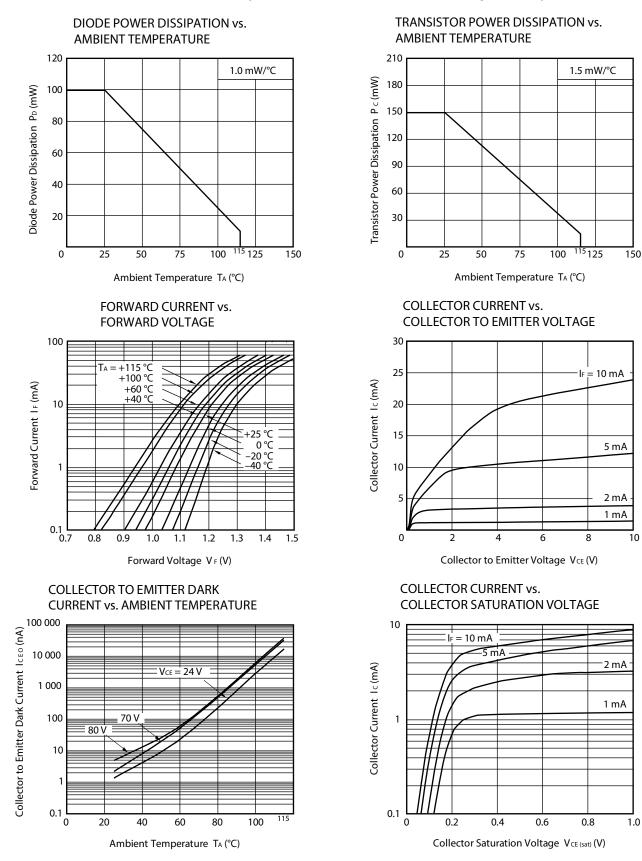
CTR rank	CTR (%)	Conditions
W	130 to 260	I⊧ = 5 mA, Vcε = 5 V
	20 to	I⊧ = 1 mA, Vcε = 5 V
L	100 to 300	I⊧ = 5 mA, Vcε = 5 V
	20 to	I⊧ = 1 mA, Vcε = 5 V
М	50 to 150	I⊧ = 5 mA, Vcε = 5 V
	10 to	I⊧ = 1 mA, Vcε = 5 V
N	50 to 400	I⊧ = 5 mA, Vcε = 5 V
	10 to	I _F = 1 mA, V _{CE} = 5 V

*2. Test circuit for switching time

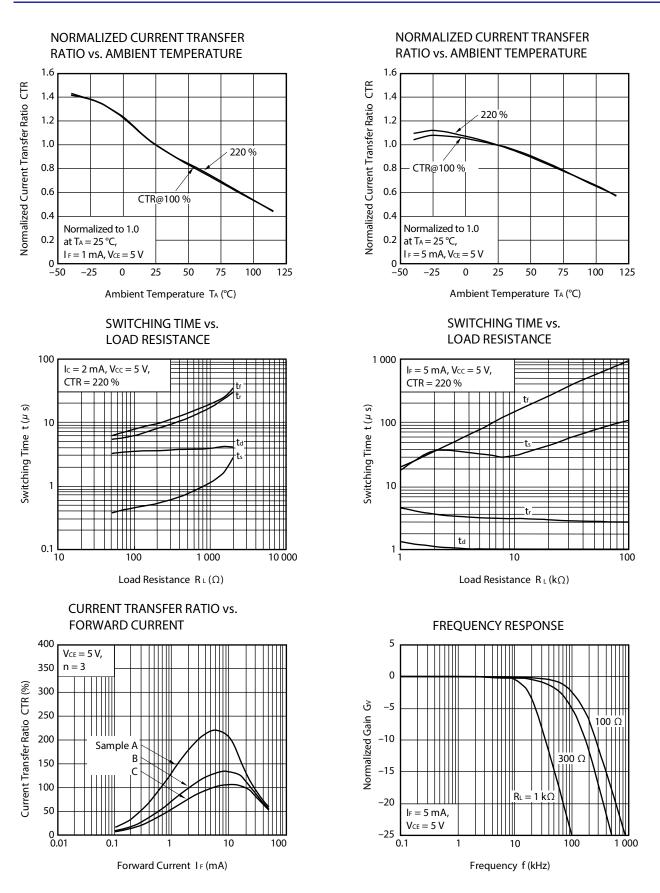


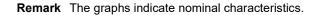


TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)



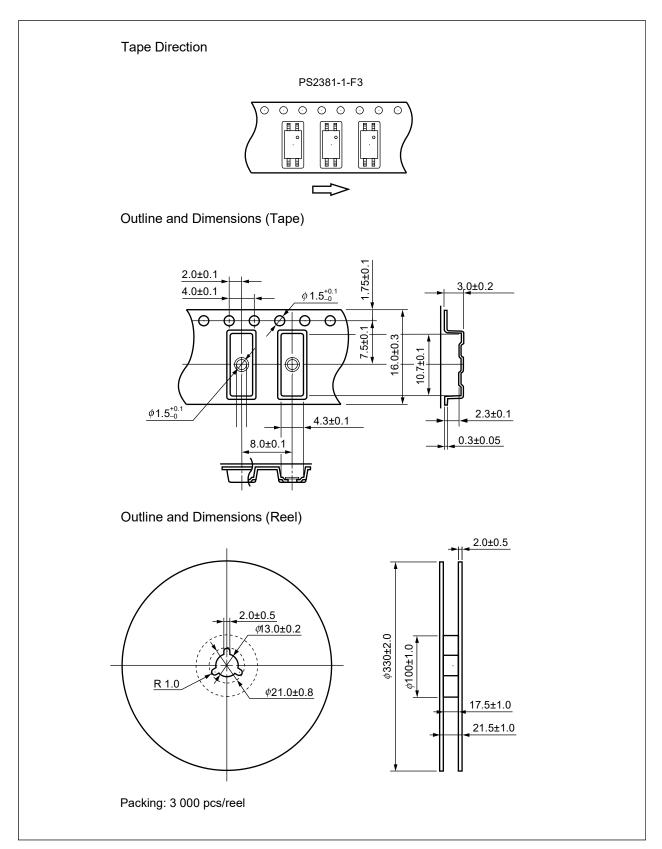




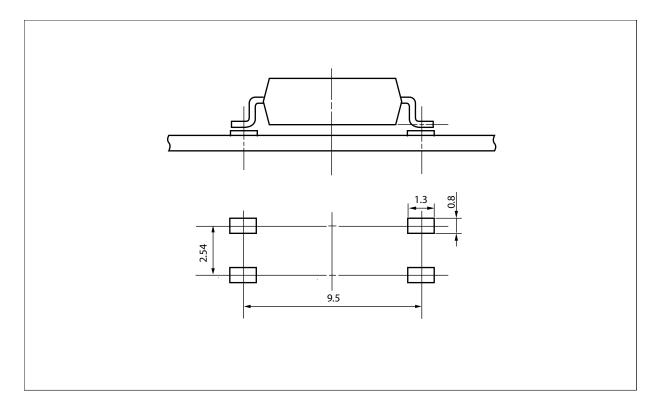




TAPING SPECIFICATIONS (UNIT: mm)



RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

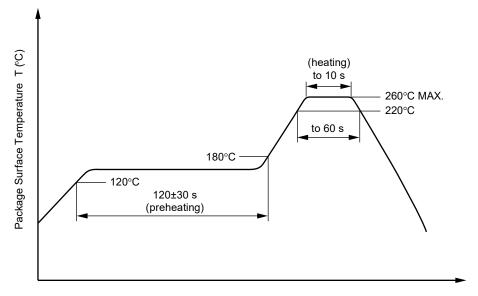


NOTES ON HANDLING

- 1. Recommended soldering conditions
 - (1) Infrared reflow soldering
 - Peak reflow temperature
 - Time of peak reflow temperature
 - Time of temperature higher than 220°C
 - Time to preheat temperature from 120 to 180°C
 - Number of reflows
 - Flux

260 °C or below (package surface temperature) 10 seconds or less 60 seconds or less 120±30 s Three Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

- (2) Wave soldering
 - Temperature 260 °C or below (molten solder temperature)
 - Time 10 seconds or less
 - Preheating conditions 120 °C or below (package surface temperature)
 - Number of times One (Allowed to be dipped in solder including plastic mold portion.)
 - Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

Time (each pins)

• Peak Temperature (lead part temperature) 350 °C or below

3 seconds or less

• Flux

Flux

Rosin flux containing small amount of chlorine

(The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100 °C

(4) Cautions

Flux Cleaning

Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.

• Do not use fixing agents or coatings containing halogen-based substances.



2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

 Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

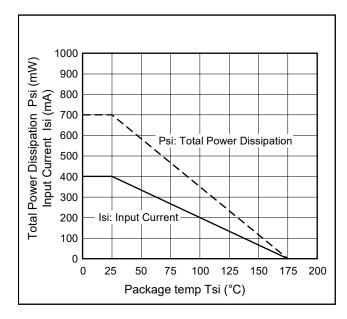
- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.
- 3. Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- 4. Do not use fixing agents or coatings containing halogen-based substances.



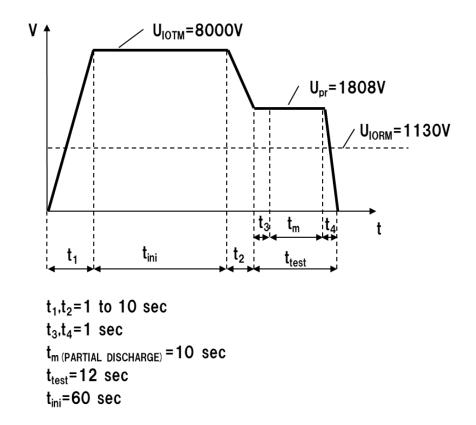
SPECIFICATION O	F VDE	MARKS	LICENSE	DOCUMENT
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Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/115/21	
Dielectric strength			
maximum operating isolation voltage	UIORM	1 130	Vpeak
Test voltage (partial discharge test, procedure a for type test and random test)	Upr	1 808	Vpeak
U_{pr} = 1.6 × UIORM, Pd < 5 pC			
Test voltage (partial discharge test, procedure b for all devices)	Upr	2 119	Vpeak
U_{pr} = 1.875 × UIORM, Pd < 5 pC			
Highest permissible overvoltage	Utr	8 000	Vpeak
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	CTI	175	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		llla	
Storage temperature range	Tstg	-40 to +125	°C
Operating temperature range	TA	-40 to +115	°C
Isolation resistance, minimum value			
Vio = 500 V dc at T _A = 25°C	Ris MIN.	10 ¹²	Ω
Vio = 500 V dc at T _A MAX. at least 100°C	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating			
curve)			
Package temperature	Tsi	175	°C
Current (input current I⊧, Psi = 0)	lsi	400	mA
Power (output or total power dissipation)	Psi	700	mW
Isolation resistance			
V _I o = 500 V dc at T _A = Tsi	Ris MIN.	10 ⁹	Ω

Dependence of maximum safety ratings with package temperature

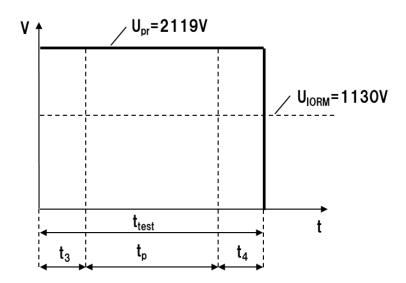






Method a) Destructive Test, Type and Sample Test

Method b) Non-destructive Test, 100% Production Test



 $t_3, t_4 = 0.1$ sec $t_{p (PARTIAL DISCHARGE)} = 1.0$ sec $t_{test} = 1.2$ sec

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	 Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	• Do not lick the product or i any way allow it to enter the mouth.



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